



NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856W-BC858W
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BC846BWQ–BC847CWQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

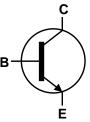
Mechanical Data

- Package: SOT323
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)

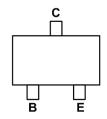
SOT323







Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

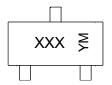
Part Number	Compliance	Dookogo	Marking	Bool Size (inches)	Packing		
Part Number	Compliance	Package	Marking	Reel Size (inches)	Qty.	Carrier	
BC846AW-7-F	Standard	SOT323	K1Q	7	3,000	Reel	
BC846BW-7-F	Standard	SOT323	K1R	7	3,000	Reel	
BC846BWQ-7-F	Automotive	SOT323	K1R	7	3,000	Reel	
BC846BW-13-F	Standard	SOT323	K1R	13	10,000	Reel	
BC847AW-7-F	Standard	SOT323	K1Q	7	3,000	Reel	
BC847BW-7-F	Standard	SOT323	K1R	7	3,000	Reel	
BC847BW-13-F	Standard	SOT323	K1R	13	10,000	Reel	
BC847BWQ-13-F	Automotive	SOT323	K1R	13	10,000	Reel	
BC847CW-7-F	Standard	SOT323	K1M	7	3,000	Reel	
BC847CW-13-F	Standard	SOT323	K1M	13	10,000	Reel	
BC847CWQ-7-F	Automotive	SOT323	K1M	7	3,000	Reel	
BC848AW-7-F	Standard	SOT323	K1Q	7	3,000	Reel	
BC848BW-7-F	Standard	SOT323	K1R	7	3,000	Reel	
BC848CW-7-F	Standard	SOT323	K1M	7	3,000	Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



XXX = Product Type Marking Code (Please See Ordering Information) YM = Date Code Marking Y or \overline{Y} = Year (ex: J = 2022) M or \overline{M} = Month (ex: 2 = February)

Date Code Key

Year	2003		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Р		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
											N	

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	Vсво	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V _{CEO}	45	V
	BC848		30	
Emitter Dage Veltage	BC846, BC847		6	V
Emitter-Base Voltage	BC848	VEBO	5	V
Continuous Collector Current		Ic	100	mA
Peak Collector Current		Ісм	200	mA
Peak Base Current		Івм	200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient	(Note 5)	R _{0JA}	625	°C/W
Thermal Resistance, Junction to Case	(Note 5)	R ₀ JC	115	°C/W
Operating and Storage Temperature Range	•	TJ, TSTG	-65 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Char	acteristic			Symbol	Min	Тур	Max	Unit	Test Condition	
BC			BC846		80					
Collector-Base Breakdown Voltage			BC847	BV_CBO	50	_	_	V	$I_C = 100\mu A$	
		E	BC848		30					
		Е	BC846		65					
Collector-Emitter Breakdown	Voltage (Note 7)	Е	BC847	BVceo	45	_	_	V	$I_C = 10mA$	
		E	BC848		30					
Emitter-Base Breakdown Vol	tago	BC84	46, BC847	D\/== a	6			V	I= 100A	
Litilitei-Dase Dieakuowii voi	ıay e	E	BC848	BV _{EBO}	5	_		V	I _E = 100μA	
			Α		110	180	220			
DC Current Gain (Note 7)	Current Gain Gro	oup	В	h _{FE}	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$	
			С		420	520	800			
Callantan Costaff Commant				Ісво	_	_	20	nA	V _{CB} = 30V	
Collector Cutoff Current							5	μA	VcB = 30V, TA = +150°C	
Collector Emitter Coturation	/altaga (Nota 7)			VCE(sat)	_	90	250	mV	$I_C = 10mA$, $I_B = 0.5mA$	
Collector-Emitter Saturation \	voitage (Note 7)					200	600	IIIV	I _C = 100mA, I _B = 5.0mA	
Base-Emitter Turn-on Voltage	o (Noto 7)			VBE(on)	580	660	700	mV	Ic = 2mA, VcE = 5V	
base-Emiller Turn-on Vollage	e (Note 7)				_	_	770	IIIV	$I_C = 10mA$, $V_{CE} = 5V$	
Raco Emittor Saturation Volta	ago (Noto 7)			V		700		mV	$I_C = 10mA, I_B = 0.5mA$	
Base-Emitter Saturation Voltage (Note 7)			V _{BE} (sat)			900		IIIV	Ic = 100mA, I _B = 5mA	
Output Capacitance				Cobo	_	3	4.5	pF	V _{CB} = 10V, f = 1.0MHz	
Transition Frequency			f⊤	100	300	_	MHz	V _{CE} = 5V, I _C = 10mA f = 100MHz		
Noise Figure				NF	_	_	10	dB	$V_{CE} = 5V, \ I_{C} = 200\mu A$ $R_{S} = 2k\Omega, \ f = 1kHz$ $\Delta f = 200Hz$	

Note:

7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

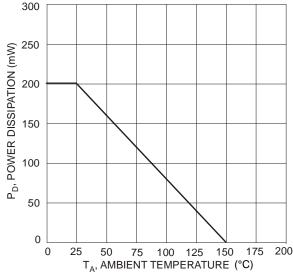


Figure 1 Power Dissipation vs. Ambient Temperature

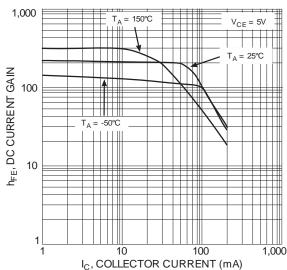


Figure 3 Typical DC Current Gain vs. Collector Current (Band A Group Gain)

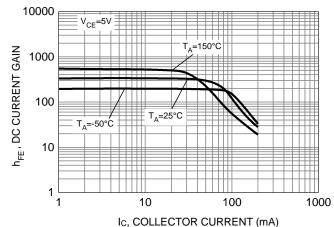


Figure 5 Typical DC Current Gain vs. Collector Current (Band B Group Gain)

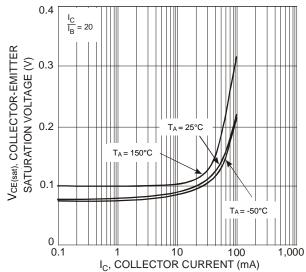


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

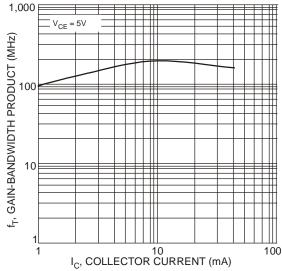
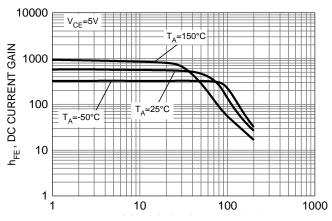


Figure 4 Typical Gain-Bandwidth Product vs. Collector Current



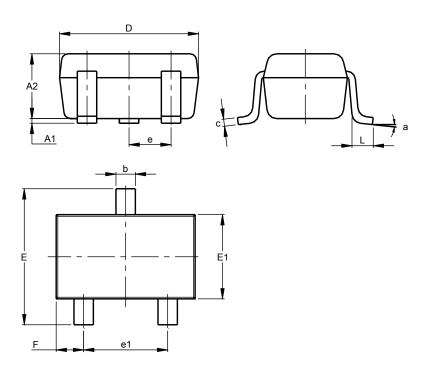
I_C, COLLECTOR CURRENT (mA)
Figure 6 Typical DC Current Gain vs. Collector Current
(Band C Group Gain)



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

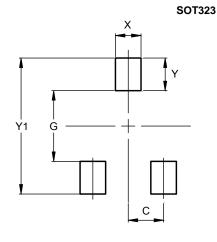
SOT323



SOT323									
Dim	Min	Min Max Typ							
A1	0.00	0.10	0.05						
A2	0.90	1.00	0.95						
b	0.25	0.40	0.30						
С	0.10	0.18	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
е	0.650 BSC								
e1	1.20	1.40	1.30						
F	0.375	0.475	0.425						
L	0.25	0.40	0.30						
а	0°	8°							
All	All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)				
С	0.650				
G	1.300				
Х	0.470				
Y	0.600				
Y1	2 500				



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